# UMENTS

Data sheet acquired from Harris Semiconductor SCHS280C

November 1997 - Revised July 2003

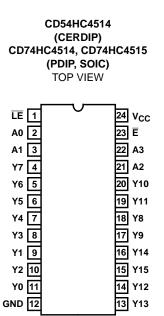
# CD54HC4514, CD74HC4514, **CD74HC4515**

## High-Speed CMOS Logic 4- to 16-Line **Decoder/Demultiplexer with Input Latches**

## Features

- Multifunction Capability
  - Binary to 1-of-16 Decoder
  - 1-to-16 Line Demultiplexer
- Fanout (Over Temperature Range)
  - Standard Outputs ..... 10 LSTTL Loads
  - Bus Driver Outputs ..... 15 LSTTL Loads
- Wide Operating Temperature Range .... -55°C to 125°C
- Balanced Propagation Delay and Transition Times
- Significant Power Reduction Compared to LSTTL Logic ICs
- HC Types
  - 2V to 6V Operation
  - High Noise Immunity: NIL = 30%, NIH = 30% of V<sub>CC</sub> at  $V_{CC} = 5V$

## Pinout



## Description

The CD54HC4514, CD74HC4514, and CD74HC4515 are high-speed silicon gate devices consisting of a 4-bit strobed latch and a 4- to 16-line decoder. The selected output is enabled by a low on the enable input  $(\overline{E})$ . A high on  $\overline{E}$  inhibits selection of any output. Demultiplexing is accomplished by using the  $\overline{E}$  input as the data input and the select inputs (A0-A3) as addresses. This  $\overline{E}$  input also serves as a chip select when these devices are cascaded.

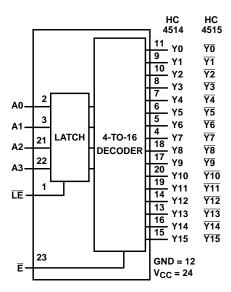
When Latch Enable  $(\overline{LE})$  is high the output follows changes in the inputs (see truth table). When  $\overline{\text{LE}}$  is low the output is isolated from changes in the input and remains at the level (high for the 4514, low for the 4515) it had before the latches were enabled. These devices, enhanced versions of the equivalent CMOS types, can drive 10 LSTTL loads.

## Ordering Information

PART NUMBER	TEMP. RANGE ( <sup>o</sup> C)	PACKAGE
CD54HC4514F3A	-55 to 125	24 Ld CERDIP
CD74HC4514E	-55 to 125	24 Ld PDIP
CD74HC4514EN	-55 to 125	24 Ld PDIP
CD74HC4514M	-55 to 125	24 Ld SOIC
CD74HC4514M96	-55 to 125	24 Ld SOIC
CD74HC4515E	-55 to 125	24 Ld PDIP
CD74HC4515EN	-55 to 125	24 Ld PDIP
CD74HC4515M	-55 to 125	24 Ld SOIC
CD74HC4515M96	-55 to 125	24 Ld SOIC

NOTE: When ordering, use the entire part number. The suffix 96 denotes tape and reel.

# Functional Diagram



DECODE TRUTH TABLE ( $\overline{LE} = 1$ )

		DECODE	R INPUTS		ADDRESSED OUTPUT
ENABLE	A3	A2	A1	A0	4514 = LOGIC 1 (HIGH) 4515 = LOGIC 0 (HIGH)
0	0	0	0	0	Y0
0	0	0	0	1	Y1
0	0	0	1	0	Y2
0	0	0	1	1	Y3
0	0	1	0	0	Y4
0	0	1	0	1	Y5
0	0	1	1	0	Y6
0	0	1	1	1	Y7
0	1	0	0	0	Y8
0	1	0	0	1	Y9
0	1	0	1	0	Y10
0	1	0	1	1	Y11
0	1	1	0	0	Y12
0	1	1	0	1	Y13
0	1	1	1	0	Y14
0	1	1	1	1	Y15
1	х	х	x	х	All Outputs = 0, 4514 All Outputs = 1, 4515

X = Don't Care; Logic 1 = High; Logic 0 = Low

#### **Absolute Maximum Ratings**

DC Supply Voltage, V <sub>CC</sub> 0.5V to 7V DC Input Diode Current, $I_{\rm IK}$
For $V_1 < -0.5V$ or $V_1 > V_{CC} + 0.5V$ ±20mA
DC Output Diode Current, I <sub>OK</sub>
For $V_O < -0.5V$ or $V_O > V_{CC} + 0.5V$ ±20mA
DC Drain Current, per Output, $I_{\Omega}$
For -0.5V < V <sub>O</sub> < V <sub>CC</sub> + 0.5V±25mA
DC Output Source or Sink Current per Output Pin, IO
For $V_0 > -0.5V$ or $V_0 < V_{CC} + 0.5V$
DC V <sub>CC</sub> or Ground Current, I <sub>CC</sub> ±50mA

### **Operating Conditions**

Temperature Range ( $T_A$ )
Supply Voltage Range, V <sub>CC</sub>
HC Types
DC Input or Output Voltage, V <sub>I</sub> , V <sub>O</sub> 0V to V <sub>CC</sub>
Input Rise and Fall Time
2V
4.5V 500ns (Max)
6V

#### **Thermal Information**

Thermal Resistance (Typical)	θ <sub>JA</sub> ( <sup>o</sup> C/W)
E (PDIP) Package (Note 1)	67
EN (PDIP) Package (Note 1)	67
M (SOIC) Package (Note 2)	46
Maximum Junction Temperature	150 <sup>0</sup> C
Maximum Storage Temperature Range	65 <sup>0</sup> C to 150 <sup>0</sup> C
Maximum Lead Temperature (Soldering 10s)	
(SOIC - Lead Tips Only)	

CAUTION: Stresses above those listed in "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress only rating and operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied.

#### NOTES:

1. The package thermal impedance is calculated in accordance with JESD 51-3.

2. The package thermal impedance is calculated in accordance with JESD 51-7.

		TES CONDI		V <sub>CC</sub>		25 <sup>0</sup> C		-40°C T	O 85°C	-55°C T	0 125°C	
PARAMETER	SYMBOL	V <sub>I</sub> (V)	I <sub>O</sub> (mA)	(V)	MIN	TYP	MAX	MIN	MAX	MIN	MAX	UNITS
HC TYPES	-				-			-				
High Level Input Voltage	VIH	-	-	2	1.5	-	-	1.5	-	1.5	-	V
				4.5	3.15	-	-	3.15	-	3.15	-	V
				6	4.2	-	-	4.2	-	4.2	-	V
Low Level Input Voltage	VIL	-	-	2	-	-	0.5	-	0.5	-	0.5	V
				4.5	-	-	1.35	-	1.35	-	1.35	V
				6	-	-	1.8	-	1.8	-	1.8	V
High Level Output	V <sub>OH</sub>	$V_{\text{IH}}$ or $V_{\text{IL}}$	-0.02	2	1.9	-	-	1.9	-	1.9	-	V
Voltage CMOS Loads			-0.02	4.5	4.4	-	-	4.4	-	4.4	-	V
			-0.02	6	5.9	-	-	5.9	-	5.9	-	V
High Level Output	1		-	-	-	-	-	-	-	-	-	V
Voltage TTL Loads			-4	4.5	3.98	-	-	3.84	-	3.7	-	V
			-5.2	6	5.48	-	-	5.34	-	5.2	-	V

#### **DC Electrical Specifications**

## CD54HC4514, CD74HC4514, CD74HC4515

## DC Electrical Specifications (Continued)

		TEST CONDITIONS		v <sub>cc</sub>		25 <sup>0</sup> C		-40°C TO 85°C		-55°C TO 125°C		
PARAMETER	SYMBOL	V <sub>I</sub> (V)	I <sub>O</sub> (mA)	(V)	MIN	ТҮР	MAX	MIN	MAX	MIN	MAX	UNITS
Low Level Output	V <sub>OL</sub>	$V_{\text{IH}} \text{ or } V_{\text{IL}}$	0.02	2	-	-	0.1	-	0.1	-	0.1	V
Voltage CMOS Loads	\$		0.02	4.5	-	-	0.1	-	0.1	-	0.1	V
		0.02	6	-	-	0.1	-	0.1	-	0.1	V	
Low Level Output	1		-	-	-	-	-	-	-	-	-	V
Voltage TTL Loads			4	4.5	-	-	0.26	-	0.33	-	0.4	V
			5.2	6	-	-	0.26	-	0.33	-	0.4	V
Input Leakage Current	Ц	V <sub>CC</sub> or GND	-	6	-	-	±0.1	-	±1	-	±1	μA
Quiescent Device Current	Icc	V <sub>CC</sub> or GND	0	6	-	-	8	-	80	-	160	μA

## Prerequisite For Switching Specifications

		TEST	v <sub>cc</sub>		25 <sup>0</sup> C		-40 <sup>0</sup> C T	O 85°C	-55°C T	O 125 <sup>0</sup> C	
PARAMETER	SYMBOL	CONDITIONS	(V)	MIN	ТҮР	MAX	MIN	MAX	MIN	MAX	UNITS
HC TYPES			-			-					
LE Pulse Width	t <sub>W</sub>	-	2	75	-	-	95	-	110	-	ns
			4.5	30	-	-	19	-	22	-	ns
			6	35	-	-	16	-	19	-	ns
Select to LE Set-Up Time	ts∪	-	2	100	-	-	125	-	150	-	ns
			4.5	20	-	-	25	-	30	-	ns
			6	17	-	-	21	-	26	-	ns
Select to LE Hold Time	t <sub>H</sub>	-	2	0	-	-	0	-	0	-	ns
			4.5	0	-	-	0	-	0	-	ns
			6	0	-	-	0	-	0	-	ns

## Switching Specifications $C_L = 50pF$ , Input $t_r$ , $t_f = 6ns$

		TEST	TEST		25 <sup>0</sup> C			-40 <sup>о</sup> С ТО 85 <sup>о</sup> С		-55 <sup>°</sup> C TO 125 <sup>°</sup> C	
PARAMETER	SYMBOL	CONDITIONS	V <sub>CC</sub> (V)	MIN	ТҮР	MAX	MIN	MAX	MIN	MAX	UNITS
HC TYPES						-					-
Propagation Delay	t <sub>PHL</sub> , t <sub>PLH</sub>	$C_L = 50 pF$									
Select to Outputs			2	-	-	275	-	345	-	415	ns
			4.5	-	-	55	-	69	-	83	ns
		C <sub>L</sub> = 15pF	5	-	23	-	-	-	-	-	ns
		$C_L = 50 pF$	6	-	-	47	-	59	-	71	ns
LE to Outputs	t <sub>PHL</sub> , t <sub>PLH</sub>	$C_L = 50 pF$	2	-	-	225	-	280	-	340	ns
			4.5	-	-	45	-	56	-	68	ns
		C <sub>L</sub> = 15pF	5	-	19	-	-	-	-	-	ns
		C <sub>L</sub> = 50pF	6	-	-	38	-	48	-	58	ns

		TEST		25 <sup>0</sup> C			-40 <sup>о</sup> С ТО 85 <sup>о</sup> С		-55°C TO 125°C			
PARAMETER	SYMBOL	CONDITIONS	V <sub>CC</sub> (V)	MIN	TYP	MAX	MIN	MAX	MIN	MAX		
$\overline{E}$ to Outputs	t <sub>PHL,</sub> t <sub>PLH</sub>	$C_L = 50 pF$	2	-	-	175	-	220	-	265	ns	
			4.5	-	-	35	-	44	-	53	ns	
		C <sub>L</sub> = 15pF	5	-	14	-	-	-	-	-	ns	
		C <sub>L</sub> = 50pF	6	-	-	30	-	37	-	45	ns	
Output Transition Time	t <sub>THL</sub> , t <sub>TLH</sub>	C <sub>L</sub> = 50pF	2	-	-	75	-	95	-	110	ns	
			4.5	-	-	15	-	19	-	22	ns	
			6	-	-	13	-	16	-	19	ns	
Input Capacitance	C <sub>IN</sub>	C <sub>L</sub> = 50pF	-	10	-	10	-	10	-	10	pF	
Power Dissipation Capacitance (Notes 3, 4)	C <sub>PD</sub>	-	5	-	70	-	-	-	-	-	pF	

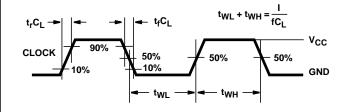
#### **Switching Specifications** $C_L = 50 pF$ , Input $t_f$ , $t_f = 6 ns$ (Continued)

NOTES:

3.  $C_{PD}$  is used to determine the dynamic power consumption, per package.

4.  $P_D = V_{CC}^2 f_i (C_{PD} + C_L)$  where  $f_i$  = Input Frequency,  $C_L$  = Output Load Capacitance,  $V_{CC}$  = Supply Voltage.

## Test Circuits and Waveforms



NOTE: Outputs should be switching from 10% V<sub>CC</sub> to 90% V<sub>CC</sub> in accordance with device truth table. For  $f_{MAX}$ , input duty cycle = 50%.

#### FIGURE 1. HC CLOCK PULSE RISE AND FALL TIMES AND PULSE WIDTH

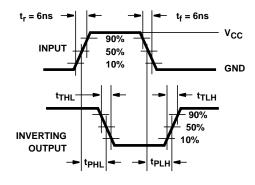
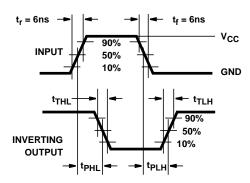
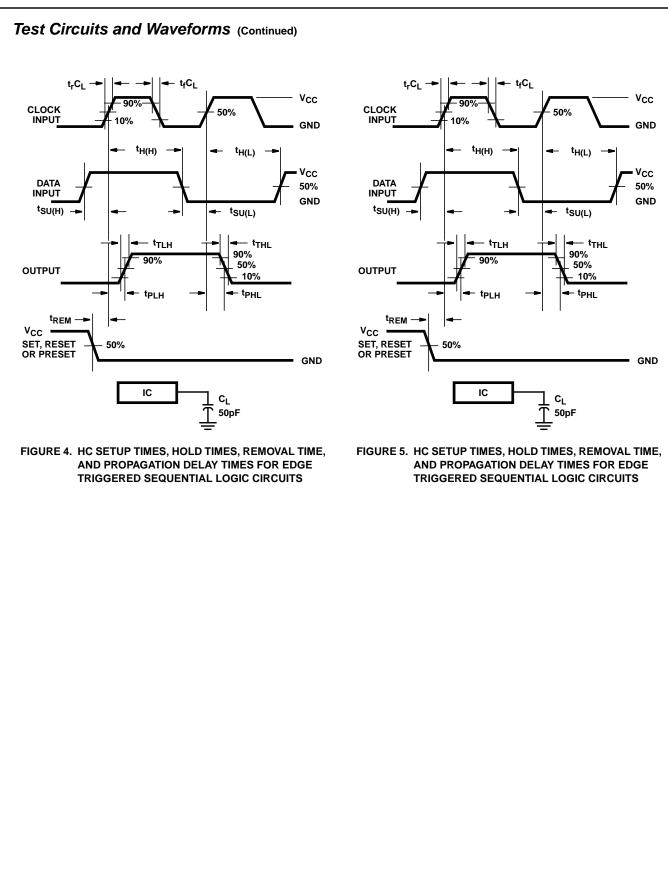


FIGURE 2. HC TRANSITION TIMES AND PROPAGATION DELAY TIMES, COMBINATION LOGIC



#### FIGURE 3. HC TRANSITION TIMES AND PROPAGATION DELAY TIMES, COMBINATION LOGIC





9-May-2014

## **PACKAGING INFORMATION**

Orderable Device	Status	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead/Ball Finish (6)	MSL Peak Temp	Op Temp (°C)	Device Marking (4/5)	Samples
5962-9865501QJA	ACTIVE	CDIP	J	24	1	TBD	Call TI	N / A for Pkg Type	-55 to 125	5962-9865501QJ A CD54HC4514F3A	Samples
CD54HC4514F3A	ACTIVE	CDIP	J	24	1	TBD	Call TI	N / A for Pkg Type	-55 to 125	5962-9865501QJ A CD54HC4514F3A	Samples
CD74HC4514E	ACTIVE	PDIP	N	24	15	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type	-55 to 125	CD74HC4514E	Samples
CD74HC4514EE4	ACTIVE	PDIP	N	24	15	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type	-55 to 125	CD74HC4514E	Samples
CD74HC4514EN	ACTIVE	PDIP	NT	24	15	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type	-55 to 125	CD74HC4514EN	Samples
CD74HC4514ENE4	ACTIVE	PDIP	NT	24	15	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type	-55 to 125	CD74HC4514EN	Samples
CD74HC4514M	ACTIVE	SOIC	DW	24	25	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-55 to 125	HC4514M	Samples
CD74HC4514M96	ACTIVE	SOIC	DW	24	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-55 to 125	HC4514M	Samples
CD74HC4514M96E4	ACTIVE	SOIC	DW	24		TBD	Call TI	Call TI	-55 to 125	HC4514M	Samples
CD74HC4514M96G4	ACTIVE	SOIC	DW	24		TBD	Call TI	Call TI	-55 to 125	HC4514M	Samples
CD74HC4514ME4	ACTIVE	SOIC	DW	24	25	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-55 to 125	HC4514M	Samples
CD74HC4514MG4	ACTIVE	SOIC	DW	24	25	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-55 to 125	HC4514M	Samples
CD74HC4515E	ACTIVE	PDIP	Ν	24	15	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type	-55 to 125	CD74HC4515E	Samples
CD74HC4515EE4	ACTIVE	PDIP	Ν	24	15	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type	-55 to 125	CD74HC4515E	Samples
CD74HC4515EN	ACTIVE	PDIP	NT	24	15	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type	-55 to 125	CD74HC4515EN	Samples
CD74HC4515ENE4	ACTIVE	PDIP	NT	24		TBD	Call TI	Call TI	-55 to 125	CD74HC4515EN	Samples
CD74HC4515M	ACTIVE	SOIC	DW	24	25	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-55 to 125	HC4515M	Samples



9-May-2014

Orderable Device	Status	Package Type	•	Pins	Package	Eco Plan	Lead/Ball Finish	MSL Peak Temp	Op Temp (°C)	Device Marking	Samples
	(1)		Drawing		Qty	(2)	(6)	(3)		(4/5)	
CD74HC4515M96	ACTIVE	SOIC	DW	24	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-55 to 125	HC4515M	Samples
CD74HC4515M96E4	ACTIVE	SOIC	DW	24	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-55 to 125	HC4515M	Samples
CD74HC4515M96G4	ACTIVE	SOIC	DW	24		TBD	Call TI	Call TI	-55 to 125	HC4515M	Samples
CD74HC4515ME4	ACTIVE	SOIC	DW	24		TBD	Call TI	Call TI	-55 to 125	HC4515M	Samples
CD74HC4515MG4	ACTIVE	SOIC	DW	24	25	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-55 to 125	HC4515M	Samples

<sup>(1)</sup> The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

**PREVIEW:** Device has been announced but is not in production. Samples may or may not be available.

**OBSOLETE:** TI has discontinued the production of the device.

<sup>(2)</sup> Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

**TBD:** The Pb-Free/Green conversion plan has not been defined.

**Pb-Free (RoHS):** TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

**Pb-Free (RoHS Exempt):** This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

<sup>(3)</sup> MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

<sup>(4)</sup> There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

<sup>(5)</sup> Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

<sup>(6)</sup> Lead/Ball Finish - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead/Ball Finish values may wrap to two lines if the finish value exceeds the maximum column width.



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9-May-2014

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#### OTHER QUALIFIED VERSIONS OF CD54HC4514, CD74HC4514 :

- Catalog: CD74HC4514
- Military: CD54HC4514

NOTE: Qualified Version Definitions:

- Catalog TI's standard catalog product
- Military QML certified for Military and Defense Applications

# PACKAGE MATERIALS INFORMATION

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## TAPE AND REEL INFORMATION

#### REEL DIMENSIONS

TEXAS INSTRUMENTS





TAPE AND REEL INFORMATION

#### TAPE DIMENSIONS



A0	Dimension designed to accommodate the component width
B0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

*/	Il dimensions are nominal												
	Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
	CD74HC4514M96	SOIC	DW	24	2000	330.0	24.4	10.75	15.7	2.7	12.0	24.0	Q1
	CD74HC4515M96	SOIC	DW	24	2000	330.0	24.4	10.75	15.7	2.7	12.0	24.0	Q1

TEXAS INSTRUMENTS

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# PACKAGE MATERIALS INFORMATION

14-Jul-2012



\*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
CD74HC4514M96	SOIC	DW	24	2000	367.0	367.0	45.0
CD74HC4515M96	SOIC	DW	24	2000	367.0	367.0	45.0

## **MECHANICAL DATA**

MCDI004A - JANUARY 1995 - REVISED NOVEMBER 1997

#### **CERAMIC DUAL-IN-LINE PACKAGE**

J (R-GDIP-T\*\*)



NOTES: A. All linear dimensions are in inches (millimeters).

- B. This drawing is subject to change without notice.
- C. Window (lens) added to this group of packages (24-, 28-, 32-, 40-pin).
- D. This package can be hermetically sealed with a ceramic lid using glass frit.
- E. Index point is provided on cap for terminal identification.



NT (R-PDIP-T\*\*) 24 pins shown

PLASTIC DUAL-IN-LINE PACKAGE



All integrations are in minimeters. Dimensioning and toil
B. This drawing is subject to change without notice.

The 28 pin end lead shoulder width is a vendor option, either half or full width.



## **MECHANICAL DATA**

MPDI008 - OCTOBER 1994

#### N (R-PDIP-T\*\*)

#### PLASTIC DUAL-IN-LINE PACKAGE

24 PIN SHOWN



NOTES: A. All linear dimensions are in inches (millimeters).

- B. This drawing is subject to change without notice.
- C. Falls within JEDEC MS-011
- D. Falls within JEDEC MS-015 (32 pin only)



DW (R-PDSO-G24)

PLASTIC SMALL OUTLINE



NOTES: A. All linear dimensions are in inches (millimeters). Dimensioning and tolerancing per ASME Y14.5M-1994.

B. This drawing is subject to change without notice.

C. Body dimensions do not include mold flash or protrusion not to exceed 0.006 (0,15).

D. Falls within JEDEC MS-013 variation AD.



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